

Important notice

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On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

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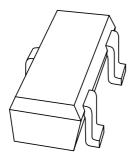
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



2PB710APNP general purpose transistor

Product data sheet Supersedes data of 1999 Apr 23 1999 May 31



NXP Semiconductors Product data sheet

PNP general purpose transistor

2PB710A

FEATURES

• High current (max. 500 mA)

• Low voltage (max. 50 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

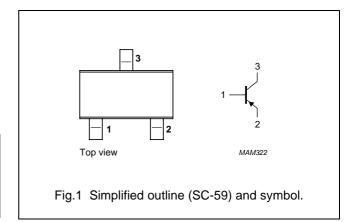
PNP transistor in an SC-59 plastic package. NPN complement: 2PD602A.

MARKING

TYPE NUMBER	MARKING CODE
2PB710AQ	DQ
2PB710AR	DR
2PB710AS	DS

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-60	V
V _{CEO}	collector-emitter voltage	open base	_	-50	V
V _{EBO}	emitter-base voltage	open collector	_	- 5	V
I _C	collector current (DC)		_	-500	mA
I _{CM}	peak collector current		_	-1	Α
I _{BM}	peak base current		_	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

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NXP Semiconductors Product data sheet

PNP general purpose transistor

2PB710A

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = -60 V	_	-10	nA
		$I_E = 0$; $V_{CB} = -60 \text{ V}$; $T_j = 150 \text{ °C}$	_	- 5	μΑ
I _{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -5 \text{ V}$	_	-10	nA
h _{FE}	DC current gain	$I_C = -150 \text{ mA}; V_{CE} = -10 \text{ V}; \text{ note 1}$			
	2PB710AQ		85	170	
	2PB710AR		120	240	
	2PB710AS		170	340	
	DC current gain	$I_C = -500 \text{ mA}; V_{CE} = -10 \text{ V}; \text{ note 1}$	40	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -300 \text{ mA}$; $I_B = -30 \text{ mA}$; note 1	_	-600	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -300 \text{ mA}$; $I_B = -30 \text{ mA}$; note 1	_	-1.5	V
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	-	15	pF
f _T	transition frequency	$I_C = -50 \text{ mA}; V_{CE} = -10 \text{ V};$			
	2PB710AQ	f = 100 MHz; note 1	100	_	MHz
	2PB710AR		120	_	MHz
	2PB710AS		140	_	MHz

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

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NXP Semiconductors Product data sheet

PNP general purpose transistor

2PB710A

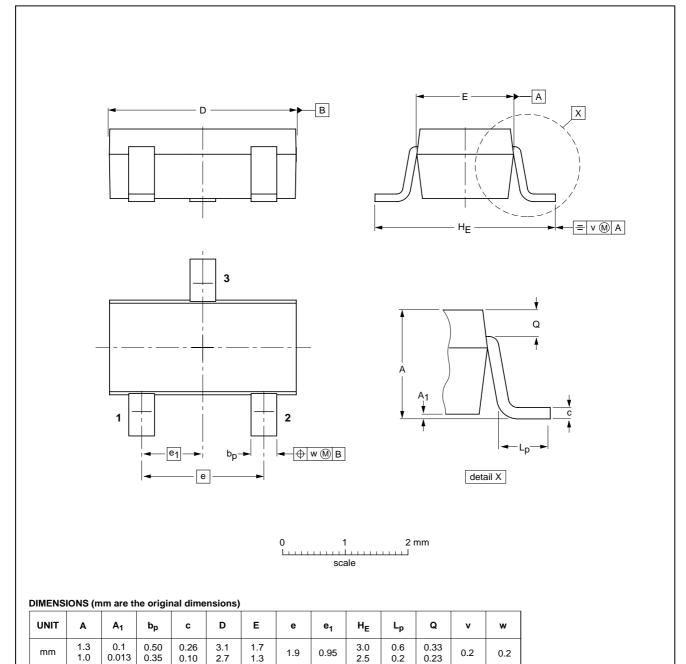
PACKAGE OUTLINE

mm

0.013

Plastic surface mounted package; 3 leads

SOT346



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT346		TO-236	SC-59			98-07-17

0.95

0.2

0.23

0.2

1.9

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PNP general purpose transistor

2PB710A

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

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